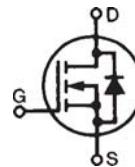


# HiPerFET™ Power MOSFETs

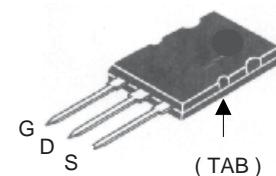
## IXFB80N50Q2

N-Channel Enhancement Mode  
Avalanche Rated, Low  $Q_g$ , Low Intrinsic  $R_G$   
High  $dV/dt$ , Low  $t_{rr}$



$V_{DSS}$  = 500V  
 $I_{D25}$  = 80A  
 $R_{DS(on)}$  ≤ 60mΩ  
 $t_{rr}$  ≤ 250ns

### PLUS264™( IXFB)



G = Gate      D = Drain  
 S = Source      TAB = Drain

### Features

- Double metal process for low gate resistance
- Unclamped Inductive Switching (UIS) rated
- Low package inductance
  - easy to drive and to protect
- Fast intrinsic rectifier

### Applications

- DC-DC converters
- Switched-mode and resonant-mode power supplies, >500kHz switching
- DC choppers
- Pulse generation
- Laser drivers

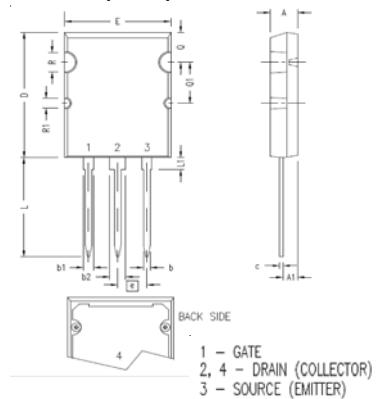
### Advantages

- PLUS 264™ package for clip or spring mounting
- Space savings
- High power density

Symbol	Test Conditions	Maximum Ratings		
$V_{DSS}$	$T_J = 25^\circ\text{C}$ to $150^\circ\text{C}$	500		V
$V_{DGR}$	$T_J = 25^\circ\text{C}$ to $150^\circ\text{C}$ , $R_{GS} = 1\text{M}\Omega$	500		V
$V_{GSS}$	Continuous	± 30		V
$V_{GSM}$	Transient	± 40		V
$I_{D25}$	$T_c = 25^\circ\text{C}$	80		A
$I_{DRMS}$	External lead limited	75		A
$I_{DM}$	$T_c = 25^\circ\text{C}$ , pulse width limited by $T_{JM}$	320		A
$I_{AR}$	$T_c = 25^\circ\text{C}$	80		A
$E_{AR}$	$T_c = 25^\circ\text{C}$	60		mJ
$E_{AS}$	$T_c = 25^\circ\text{C}$	5.0		J
$dV/dt$	$I_s \leq I_{DM}$ , $V_{DD} \leq V_{DSS}$ , $T_J \leq 150^\circ\text{C}$	20		V/ns
$P_D$	$T_c = 25^\circ\text{C}$	960		W
$T_J$		-55 ... +150		°C
$T_{JM}$		150		°C
$T_{stg}$		-55 ... +150		°C
$T_L$	1.6 mm (0.063 in.) from case for 10s	300		°C
$T_{SOLD}$	Plastic body for 10s	260		°C
$F_c$	Mounting force	30...120/6.7...27		N / lbs
<b>Weight</b>		10		g

Symbol	Test Conditions	Characteristic Values		
		( $T_J = 25^\circ\text{C}$ , unless otherwise specified)	Min.	Typ.
$BV_{DSS}$	$V_{GS} = 0\text{ V}$ , $I_D = 1\text{mA}$	500		V
$V_{GS(th)}$	$V_{DS} = V_{GS}$ , $I_D = 8\text{mA}$	3.0		V
$I_{GSS}$	$V_{GS} = \pm 30\text{ V}$ , $V_{DS} = 0\text{V}$		± 200	nA
$I_{DSS}$	$V_{DS} = V_{DSS}$ $V_{GS} = 0\text{V}$		100	μA
			5	mA
$T_J = 125^\circ\text{C}$				
$R_{DS(on)}$	$V_{GS} = 10\text{V}$ , $I_D = 0.5 \cdot I_{D25}$ , Note 1		60	mΩ

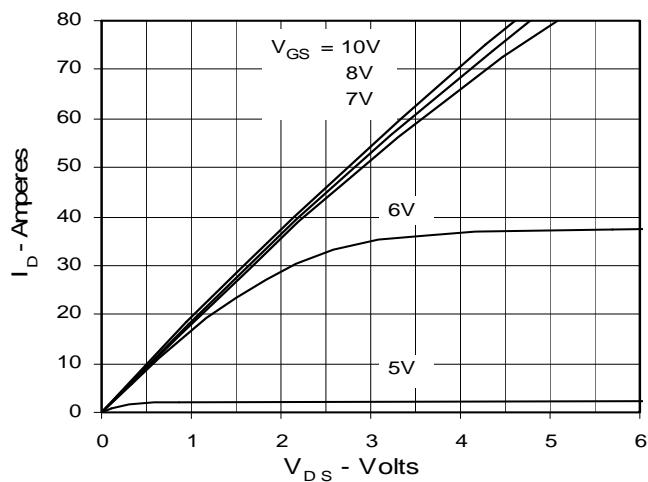
Symbol	Test Conditions ( $T_J = 25^\circ\text{C}$ , unless otherwise specified)	Characteristic Values		
		Min.	Typ.	Max.
$g_{fs}$	$V_{DS} = 10\text{V}$ , $I_D = 0.5 \cdot I_{D25}$ , Note 1	50	65	S
$C_{iss}$			15	nF
$C_{oss}$			1610	pF
$C_{rss}$			300	pF
$t_{d(on)}$	<b>Resistive Switching Times</b> $V_{GS} = 10\text{V}$ , $V_{DS} = 0.5 \cdot V_{DSS}$ , $I_D = 0.5 \cdot I_{D25}$ $R_G = 1\Omega$ (External)	29		ns
$t_r$		25		ns
$t_{d(off)}$		60		ns
$t_f$		11		ns
$Q_{g(on)}$		250		nC
$Q_{gs}$		80		nC
$Q_{gd}$		120		nC
$R_{thJC}$			0.13	°C/W
$R_{thCK}$		0.13		°C/W

**PLUS264™ (IXFB) Outline****Source-Drain Diode****Characteristic Values**(  $T_J = 25^\circ\text{C}$ , unless otherwise specified )

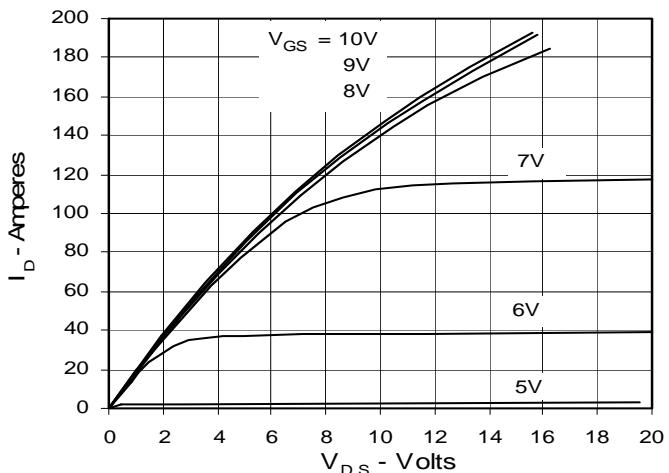
Symbol	Test Conditions	Min.	Typ.	Max.
$I_s$	$V_{GS} = 0\text{V}$		80	A
$I_{SM}$	Repetitive; pulse width limited by $T_{JM}$		320	A
$V_{SD}$	$I_F = I_S$ , $V_{GS} = 0\text{V}$ , Note 1		1.5	V
$t_{rr}$	$I_F = 25\text{A}$ , $V_{GS} = 0\text{V}$ $-di/dt = 100 \text{ A}/\mu\text{s}$ $V_R = 100 \text{ V}$		250	ns
$Q_{RM}$		1.4		μC
$I_{RM}$		12		A

Note: 1. Pulse test,  $t \leq 300\mu\text{s}$ , duty cycle,  $d \leq 2\%$ .

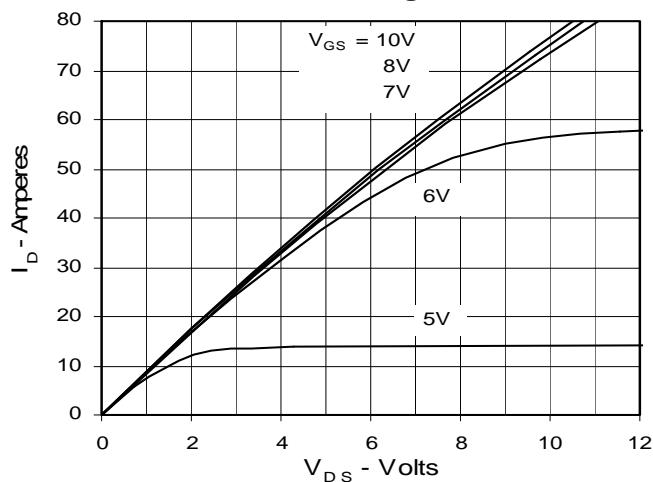
**Fig. 1. Output Characteristics  
@ 25 Deg. C**



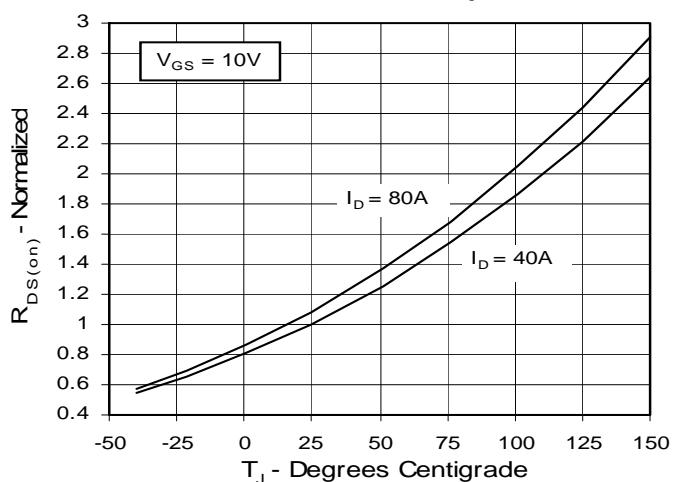
**Fig. 2. Extended Output Characteristics  
@ 25 deg. C**



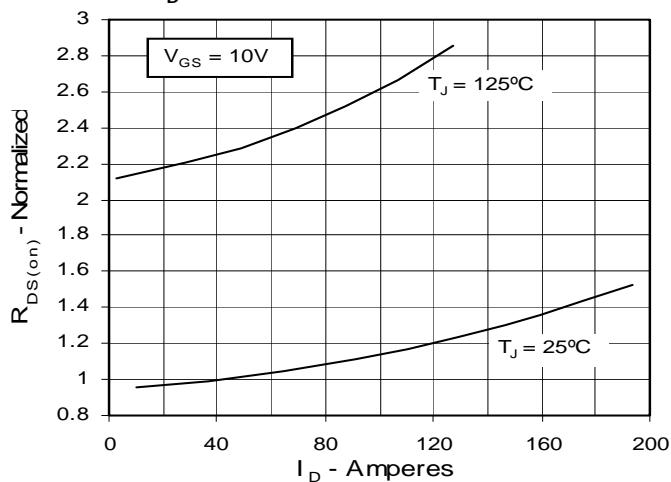
**Fig. 3. Output Characteristics  
@ 125 Deg. C**



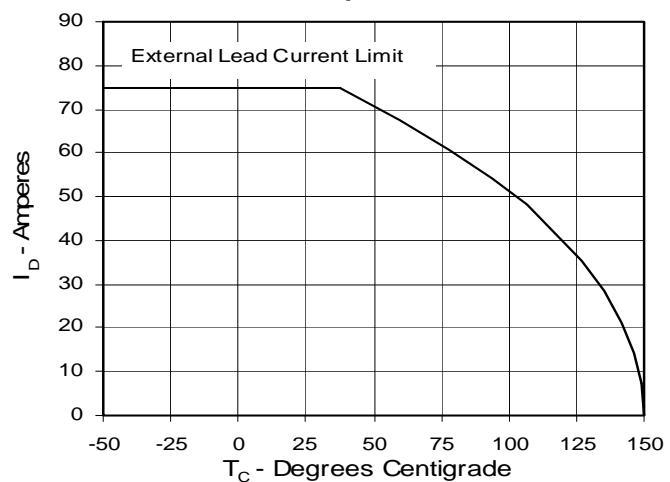
**Fig. 4.  $R_{DS(on)}$  Normalized to  $I_D = 40A$   
Value vs. Junction Temperature**

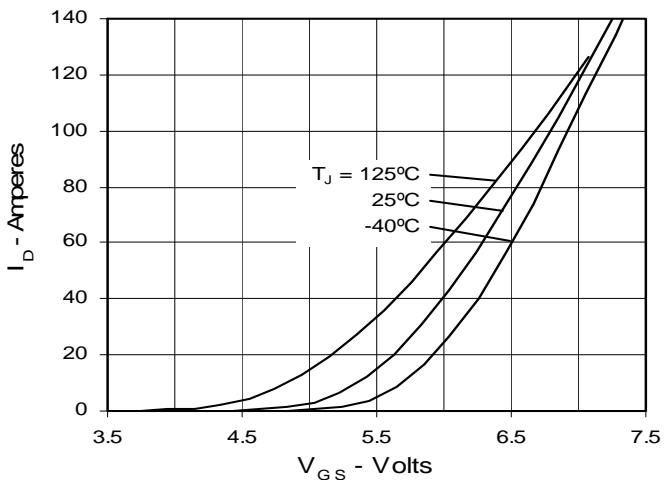
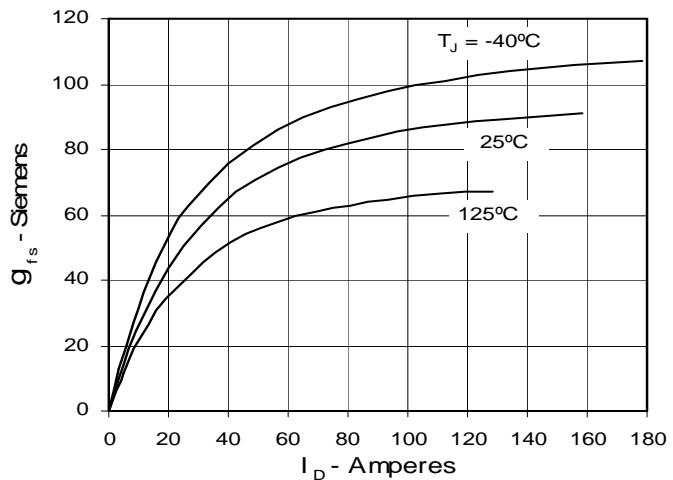
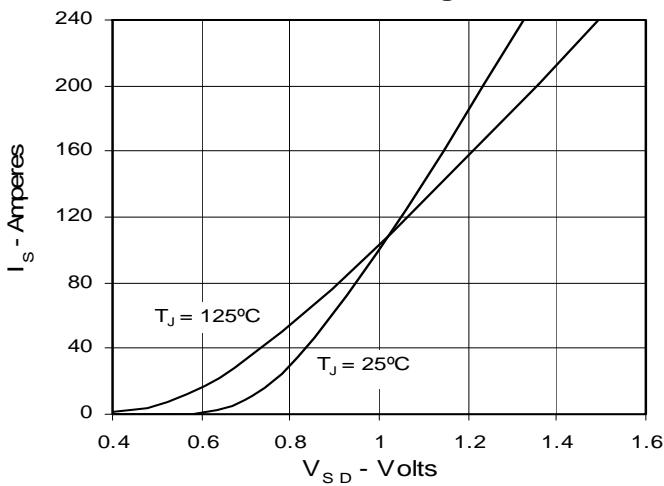
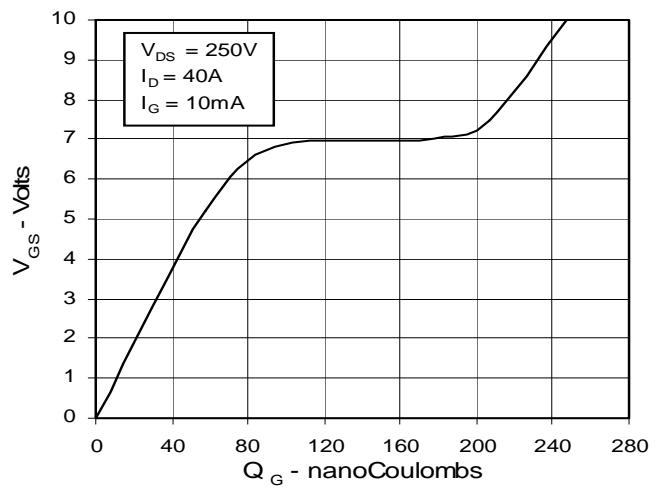
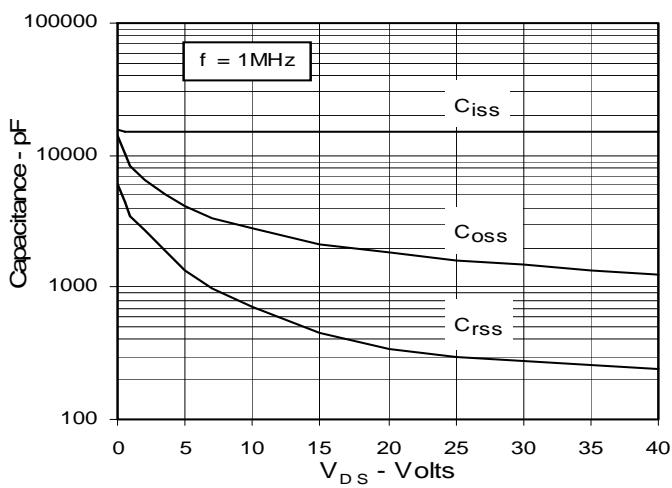


**Fig. 5.  $R_{DS(on)}$  Normalized to  
 $I_D = 40A$  Value vs. Drain Current**



**Fig. 6. Drain Current vs. Case  
Temperature**



**Fig. 7. Input Admittance****Fig. 8. Transconductance****Fig. 9. Source Current vs. Source-To-Drain Voltage****Fig. 10. Gate Charge****Fig. 11. Capacitance****Fig. 12. Maximum Transient Thermal Impedance**